Electronic structure and transport properties of La$_{0.7}$Ce$_{0.3}$MnO$_3$

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X-ray absorption spectroscopy (XAS), optical reflectance spectroscopy, and the Hall effect measurements were used to investigate the electronic structure in La$_{0.7}$Ce$_{0.3}$MnO$_3$ thin films (LCeMO). The XAS results are consistent with those obtained from LDA+U calculations. In that the doping of Ce has shifted up the Fermi level and resulted in marked shrinkage of hole pockets originally existing in La$_{0.7}$Ce$_{0.3}$MnO$_3$ (LCaMO). The Hall measurements indicate that in LCeMO the carriers are still displaying the characteristics of holes as LDA+U calculations predict. Analyses of the optical reflectance spectra evidently disapprove the scenario that the present LCeMO might have been dominated by the La-deficient phases.

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Over the last decade, researches on the rare-earth manganese perovskites R$_{1-x}$AmnO$_3$ (R: rare-earth ion, A: alkaline earth cation), have been largely devoted to the characteristics related to the electric transport and magnetic properties, e.g., colossal magnetoresistance, phase separation, and the competition between the charge, spin, and orbital order parameters.$^1$ In these compounds, the charge state of Mn displays a mixed-valence characteristic of Mn$^{3+}$ and Mn$^{4+}$, and the ratio of Mn$^{3+}$/Mn$^{4+}$ depends strongly on the doping level of the divalent cation. Intuitively, substituting the divalent cation with the tetravalent cation, such as Ce, Sn, etc., should impel the valence state of Mn to a mixed-valence state of Mn$^{2+}$ and Mn$^{3+}$. It then raises curiosities on how the electric transport and magnetic properties of tetravalent cation doped manganites would prevail, as compared with the divalent-doped system.

Previously, the transport properties and the electronic structure of LCeMO had been reported with results obtained from the tunneling junction, photoemission, and x-ray absorption spectroscopy (XAS) experiments.$^4,5$ The results showed that the valence state of Mn is indeed a mixed-valence of Mn$^{2+}$/Mn$^{3+}$, and it is probably electron doped. However, there are discrepancies among the reported results. For instance, the tunneling junction experiments suggested that the itinerant carriers in LCeMO are the minority spin carriers,$^5$ which was in sharp contrast to the conclusion of the majority spin carriers drawn from XAS experiments and theoretical calculations.$^8,9$ On the other hand, some reports even proposed that it is the La-deficient phase existing in LCeMO that gives rise to the metal-insulator transition.$^{10}$ In this paper, we have utilized various independent experimental and theoretical approaches to systematically examine the LCeMO system. Our results unambiguously clarified some of the outstanding controversies in this system.

Details of preparing the single phase LCeMO on (100) SrTiO$_3$ substrates by pulsed-laser deposition and the associated structure-property analyses were reported in Ref. 11. The x-ray scattering and x-ray diffraction results indicated that the obtained LCeMO films were highly epitaxial single-phase samples with negligible traces of impurity phases such as CeO$_2$ and MnO. The O K edge and Mn L edge XAS spectra were carried out using linear polarized synchrotron radiation from a 6-m high-energy spherical grating monochromator beamline located at NSRRC in Taiwan. Details of XAS experiments can be found in Ref. 12. Being different from previous XAS measurements at 300 K,$^5,6$ the O 1s XAS spectra of LCeMO and LCaMO were taken by x-ray fluorescence yield at 30 K, which directly probed the electronic structure in the ferromagnetic state for both samples. The longitudinal resistivity $\rho_{xx}$, and Hall resistivity $\rho_{xy}$, were measured by the four-probe and six-probe techniques, respectively. All of $\rho_{xx}$, $\rho_{xy}$, and the magnetization $M$ were measured in an 8-T QUANTUM DESIGN® physical properties measuring system (PPMS). Near-normal optical reflectance spectra were measured over a broad frequency range (from 50 to 52,000 cm$^{-1}$) at temperatures between 10 and 330 K. The thin-film optics and the Drude-Lorentz analysis were used to modeling the optical properties of these samples.$^{13}$ The band structure calculations were performed using the full-potential projected augmented wave method$^{14}$ as implemented in the Vienna ab initio simulation package (VASP) (Ref. 15) within the local-density approximation plus on-site Coulomb interaction $U$(LDA+U) scheme.$^{16}$ In the LDA+U calculations, we used Coulomb energy $U$=5.0 eV and exchange parameter $J$=0.95 eV for Ce(La)-4f electrons, while $U$=4.0 eV and $J$=0.87 eV were used for Mn-3d electrons.$^8$

To characterize the valence state of manganese in LCeMO, Mn L-edge XAS spectra of MnO$_2$, Mn$_2$O$_3$, MnO, LCaMO, and LCeMO were measured and are shown in Fig. 1(a) for comparison. The spectral weight of Mn L-edge for LCeMO evidently exhibits the characteristics of both Mn$^{2+}$ and Mn$^{3+}$, which has been previously interpreted as a manifestation of Mn$^{2+}$/Mn$^{3+}$ mixed-state in LCeMO.$^6$ In Fig. 1(b), O K-edge XAS spectrum of LCeMO reveals a shoulder
near absorption edge as compared with the first pronounced peak of LCaMO at 529 eV. These results suggest that there are fewer unoccupied states in $e_{g}↑$ band of LCeMO than in that of LCaMO due to extra electrons doped into the $e_{g}$ band of LCaMO, presumably originated from substituting Ca$^{2+}$ over, as displayed in the inset of Fig. 1. 

The next question of whether the doped electrons actually drive the itinerant carriers to become \textit{electrons} remains to be confirmed. To examine this scenario, the Hall measurements are indispensable. In ferromagnets, the Hall resistivity can be expressed by \( \rho_{xy}(B,T) = R_H(T)B + \mu_0 R_S(T)M(B,T) \), where \( R_H \) is the ordinary Hall coefficient, \( R_S \) the anomalous Hall coefficient, \( \mu_0 \) the vacuum permeability, and magnetic induction \( B = \mu_0[H + (1 - N_d)M] \) with the demagnetization factor \( N_d \approx 1 \) in our film geometry. In order to improve the accuracy of the experimental data, values of \( \rho_{xy} \) were obtained by averaging the results acquired from two scans of \( B \). The field scans range from 8 to −8 T. Combining with the measurements of \( M(B) \), \( R_H \) and \( R_S \) were then obtained by fitting \( \rho_{xy}(B) \) to the abovementioned Hall resistivity equation. As shown in Fig. 3, the positive slope \( dp_{xy}/dB \) in the high field regime, where \( M(B) \) saturates, strongly suggests that the itinerant carriers in the present LCeMO films, similar to that in LCaMO films, are \textit{holes}. In addition to the ordinary Hall effect discussed above, the extraordinary Hall effect is generally associated with large and localized magnetic moments existent in the material.\(^{17}\) As is evident in Fig. 3, LCeMO appears to have a more significant extraordinary Hall effect than LCaMO even at 10 K. The difference might be due to

![Fig. 1](image1.png)  
**Fig. 1.** (Color online) (a) Spectra of Mn L-edge XAS for Mn ions with various valence states by total electron yield. (b) Spectra of O K-edge XAS (by florescence yield) of LCaMO and LCeMO at 300 and 30 K, respectively. The absorption peaks at 529 and 530 eV were assigned to the unoccupied states of $e_{g}↑$ and $t_{2g}↑$ orbitals, respectively. Inset: \( \rho(T) \) and \( M(T) \) of LCeMO, showing the typical CMR magnetotransport characteristics. (c) Left: Schematic band diagrams describing the majority spin scenario for LCeMO (upper panel) and LCaMO (lower panel). Right: Schematic diagram, quoted from Ref. 4, depicting the minority spin carriers scenario in LCeMO.

![Fig. 2](image2.png)  
**Fig. 2.** (Color online) DOS of Mn 3d in LCaMO and LCeMO calculated by LDA+\( U \) method. The parameters used in these calculations are described in the text.
strain-induced effects could be either intrinsic (ion size difference) or extrinsic (extent of lattice mismatch with substrate). It might also be due to the difference in electronic bandwidth for the itinerant carriers, which in turn will affect the efficiency of ferromagnetic transition via the double-exchange mechanism.

We now return to the issue of the \( p \)-type behavior revealed by Hall measurements. Starting from the ionic band structure of parent \( \text{LaMnO}_3 \), due to the strong Jahn-Teller effect, the \( e_{g} \uparrow \) band splits into two subbands \( e_{g}^{1} \uparrow \) and \( e_{g}^{2} \uparrow \) and results in the commonly observed insulator behavior.\(^{18,19} \) Therefore, electron doping in \( \text{LCeMO} \) presumably could have led to electron carriers in this model. To unravel the origin of why the carriers are still holes in \( \text{LCeMO} \), we performed band structure calculations for both the hole-doped \( \text{LCaMO} \) and electron-doped \( \text{LCeMO} \) by using the LDA+\( U \) method. As shown in Fig. 4, \( \text{LCaMO} \) is clearly a \( p \)-type metal with significant hole pockets near the Fermi surface as expected. Surprisingly, the band dispersions of \( \text{LCMO} \) evidently also show nontrivial hole pockets around the Fermi surface, in spite of the electron doping from Ce\(^{4+} \) ions. Nonetheless, the Fermi level has been raised significantly in the latter case. It has been pointed out that the strong Jahn-Teller distortion due to the local lattice distortion of Mn\(^{3+} \) in \( \text{LaMnO}_3 \) is largely exempted in both of the Mn\(^{3+} \)/Mn\(^{4+} \) and Mn\(^{2+} \)/Mn\(^{3+} \) cases.\(^{1} \) Consequently, the splitting between \( e_{g}^{1} \uparrow \) and \( e_{g}^{2} \uparrow \) induced by the Jahn-Teller effect is gradually diminished when \( \text{LaMnO}_3 \) is doped with either divalent Ca or tetravalent Ce. The evolution of the electronic structure of \( \text{La}_{1−x}\text{Sr}_x\text{MnO}_3 \), which relates Jahn-Teller distortion to the hole doping level, has demonstrated the closing of the band gap between \( e_{g}^{1} \uparrow \) and \( e_{g}^{2} \uparrow \) subbands with increasing doping.\(^{19} \) We believe that it is the similar effects that lead the Fermi level of both \( \text{LCaMO} \) and \( \text{LCeMO} \) to lie in the \( e_{g} \uparrow \) band, making the transport carriers exhibit holelike behaviors in both cases.

The next issue to be addressed is whether or not all of these are just the manifestations of La-deficient phase. Since it is rather difficult to make clear-cut distinction between them by merely relying on magnetotransport and XAS measurements, we performed independent optical reflectance measurements to provide additional information for this purpose. Figure 5 shows the measured optical reflectance of the (100) \( \text{SrTiO}_3 \) substrate at 300 K and the \( \text{LCaMO}, \text{La}_{0.7}\text{MnO}_3 \) film as grown at 20 K. Both \( \text{LCaMO} \) and \( \text{La}_{0.7}\text{MnO}_3 \) film have approximately the same Curie temperature around 260 K. There are several important features to these spectra. First, the far-infrared spectrum of the \( \text{LCeMO} \) film can be described by a weak, overdamped Drude contribution typical of a poor conductor. As a consequence, the effect of multiple reflection of light in the film on the substrate is clearly seen in the midinfrared frequency region. Second, the spectral weight of the infrared reflectance of the \( \text{La}_{0.7}\text{MnO}_3 \) film is substantially increased, indicative of increased carrier concentrations. Third, from the Hall measurements and optical data, we derive the carrier effective mass of the three manganites studied by the relation \( \omega_p^2 = 4\pi e/m^*R_H \). As listed in Table I, the ratio of the effective mass \( m^* = m_\text{(LCaMO)} \) are 1.62 and 0.398 for \( \text{LCaMO} \) and \( \text{La}_{0.7}\text{MnO}_3 \) film, respectively. Consequently, \( \text{LCeMO} \) is apparently having much heavier holes and appears to be a narrow band manganite as compared to \( \text{LCaMO} \). This is in contrast to that implied by the result of \( m^* = m_\text{(LCaMO)} \) for \( \text{La}_{0.7}\text{MnO}_3 \) film shown in Table I, and virtually rules out the scenario that the \( \text{LCeMO} \) films studied in the present work is of La-deficient nature. Although Yanagida et al.\(^{10} \) reported the coexistence of nano-
TABLE I. Summary of $R_H$, $\rho$, $\omega_p$, and $m^*/m^*$ (LCaMO) for listed samples.

<table>
<thead>
<tr>
<th></th>
<th>LCeMO</th>
<th>LCaMO</th>
<th>La$_{0.7}$MnO$_3$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$R_H$ (m$^3$/C) (at 10 K)</td>
<td>$7.21 \times 10^{-10}$</td>
<td>$3.16 \times 10^{-10}$</td>
<td>$8.64 \times 10^{-10}$</td>
</tr>
<tr>
<td>$\rho$ (m$\Omega$-cm) (at 10 K)</td>
<td>5.09</td>
<td>0.366</td>
<td>1.28</td>
</tr>
<tr>
<td>$\omega_p$ (1/s) (at 20 K)</td>
<td>$4.71 \times 10^{14}$</td>
<td>$9.08 \times 10^{14}$</td>
<td>$8.63 \times 10^{14}$</td>
</tr>
<tr>
<td>$m^<em>/m^</em>$ (LCaMO)</td>
<td>1.62</td>
<td>1</td>
<td>0.398</td>
</tr>
</tbody>
</table>

cluster cerium oxides with minor phases of La-deficient La$_{1-x}$MnO$_3$ and A-site cation-deficient (La$_{1-x}$Ce$_{x}$)MnO$_3$ in their post-annealed films which showed similar metal-insulator transition, their as-grown film, albeit in single phase, was an insulator. This is different from the present as-grown LCeMO films, which are metallic even without post annealing. The differences are presumably due to different film growth processes.

In summary, we have presented the detailed results of Mn L-edge and O K-edge XAS which suggest that at low temperatures LCeMO is a majority spin carrier ferromagnet. The results also display clear evidence of electron doping into the $e_g^\uparrow$ subband of LCeMO. However, both Hall measurements and LDA+$U$ band structure calculations indicate that the doped electrons did not drive LCeMO into a n-type manganite and the itinerant carriers are still holes, but with a much less concentration as compared with that of LCaMO. Finally, the results of optical reflectance spectra, together with the Hall measurements, evidently dismiss the scenario that the present as-grown LCeMO films are dominated by La-deficient phases.

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